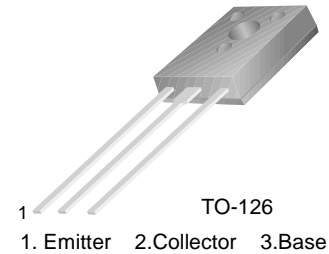


KSC2258/2258A

High Voltage General Amplifier TV Video Output Amplifier

- High BV_{CEO}



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage		
	: KSC2258	250	V
	: KSC2258A	300	V
V_{CEO}	Collector-Emitter Voltage		
	: KSC2258	250	V
	: KSC2258A	300	V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current (DC)	100	mA
I_{CP}	Collector Current (Pulse)	150	mA
P_C	Collector Dissipation ($T_C=25^\circ\text{C}$)	4	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	- 55 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E = 0.1\text{mA}, I_C = 0$	6			V
I_{CER}	Collector Cut-off Current	$V_{CE} = 250\text{V}, R_{BE} = 100\text{K}\Omega$			100	μA
h_{FE1}	DC Current Gain	$V_{CE} = 20\text{V}, I_C = 40\text{mA}$	40			
h_{FE2}		$V_{CE} = 50\text{V}, I_C = 5\text{mA}$	30			
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 50\text{mA}, I_B = 5\text{mA}$			1.2	V
$V_{BE(on)}$	Base-Emitter On Voltage	$V_{CE} = -20\text{V}, I_C = 40\text{mA}$			1.2	V
f_T	Current Gain Bandwidth Product	$V_{CE} = 10\text{V}, I_C = 10\text{mA}$		100		MHz
C_{ob}	Output Capacitance	$V_{CB} = 50\text{V}, f = 1\text{MHz}$		3	4.5	pF

Typical Characteristics

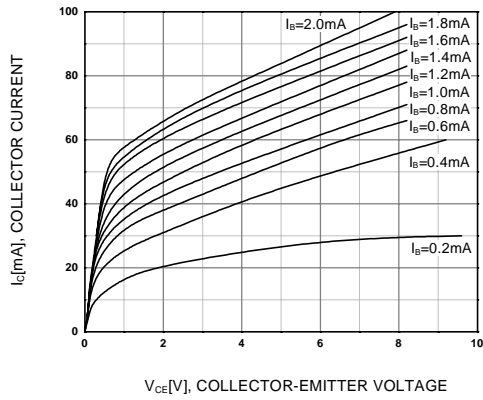


Figure 1. Static Characteristic

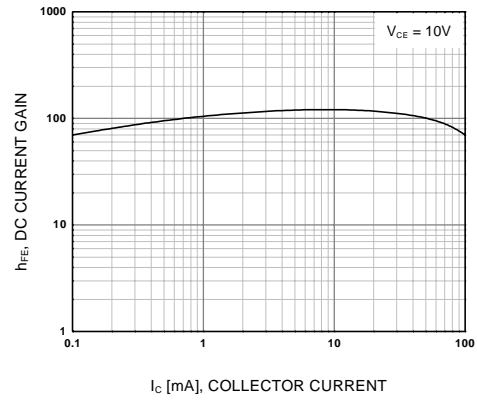


Figure 2. DC current Gain

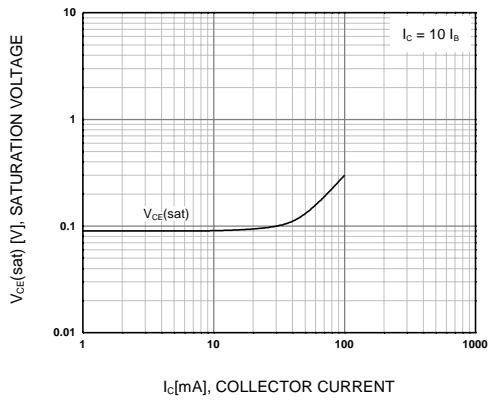


Figure 3. Collector-Emitter Saturation Voltage

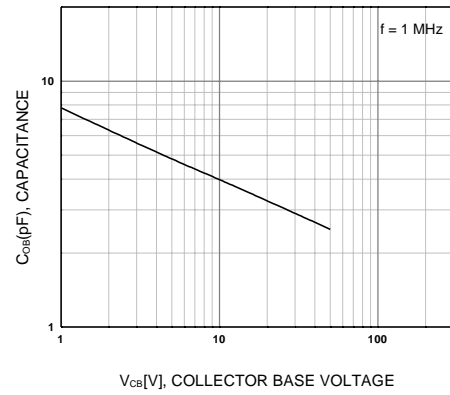


Figure 4. Collector Output Capacitance

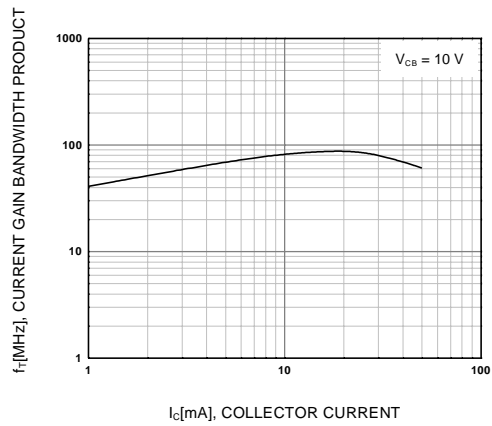


Figure 5. Current Gain Bandwidth Product

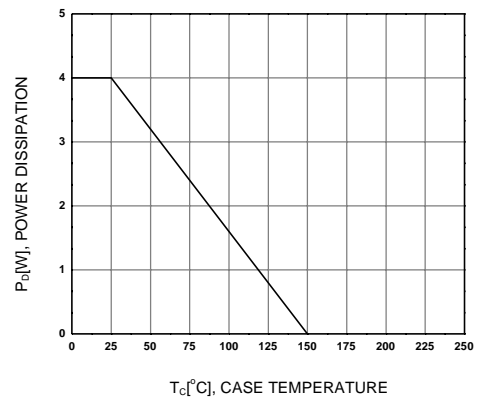
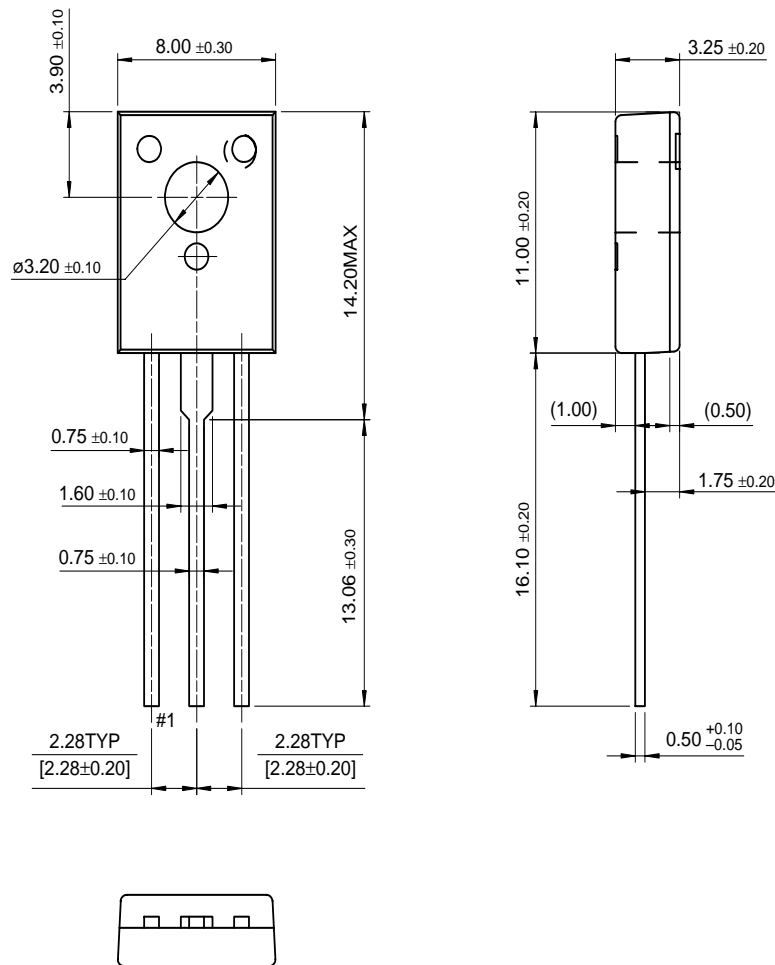


Figure 6. Power Derating

Package Dimensions

KSC2258/2258A

TO-126



Dimensions in Millimeters

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™
Bottomless™
CoolFET™
CROSSVOLT™
E²CMOS™
FACT™
FACT Quiet Series™
FAST®
FASTr™
GTO™

HiSeC™
ISOPLANAR™
MICROWIRE™
POP™
PowerTrench®
QFET™
QS™
Quiet Series™
SuperSOT™-3
SuperSOT™-6

SuperSOT™-8
SyncFET™
TinyLogic™
UHC™
VCX™

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR INTERNATIONAL.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

Fairchild Semiconductor

SEARCH | Parametric | Cross Reference

spaceProduct Folders andApplic

find products

Home >> Find products >>

Products groups

Analog and Mixed

Signal

Discrete

Interface

Logic

Microcontrollers

Non-Volatile

Memory

Optoelectronics

Markets and applications

New products

Product selection and parametric search

Cross-reference search

KSC2258

NPN Epitaxial Silicon Transistor

Contents

Features | Applications | Product status/pricing/package

Features

• High BV_{CEO}

back to top

Applications

High Voltage General Amplifier

TV Video Output Amplifier

back to top

Product status/pricing/package

Product	Product status	Pricing*	Package type	Leads	Packing method
KSC2258STU	Full Production	\$0.165	TO-126	3	RAIL

* 1,000 piece Budgetary Pricing

back to top

Related Links

Request samples

Dotted line

How to order products

Dotted line

Product Change Notices (PCNs)

Dotted line

Support

Dotted line

Distributor and field sales representatives

Dotted line

Quality and reliability

Dotted line

Design tools

technical information

buy products

technical support

my Fairchild

company

Home | Find products | Technical information | Buy products | Support | Company | Contact us | Site index | Privacy policy

© Copyright 2002 Fairchild Semiconductor